L Number	Hits	Search Text	DB	Time stamp
-	242	(257/253).CCLS.	USPAT;	2004/08/06 14:31
•			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	12	(/257/253) CCIS) and (silicon add	IBM_TDB USPAT;	2004/08/09 09:44
-	12	((257/253).CCLS.) and (silicon adj carbide)	US-PGPUB;	2004/00/09 09:44
		Carbiacy	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	((257/253).CCLS.) and (gallium adj	USPAT;	2004/08/06 14:41
		nitride)	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
-	4	(((257/253).CCLS.) and (silicon adj	USPAT;	2004/08/06 14:37
		carbide)) and passivation	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	500	/73 /31 OC) COT C	IBM_TDB	2004/00/06 14.27
-	508	(73/31.06).CCLS.	USPAT; US-PGPUB;	2004/08/06 14:37
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	10	((73/31.06).CCLS.) and (silicon adj	USPAT;	2004/08/06 14:38
		carbide)	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
_	1	((73/31.06).CCLS.) and (gallium adj	USPAT;	2004/08/06 14:38
		nitride)	US-PGPUB;	
			EPO; JPO;	
İ			DERWENT;	
	2	////73/31 06/ 0010 / / /	IBM_TDB	2004/00/06 14 41
-	2	((((73/31.06).CCLS.) and (silicon adj carbide)) or (((73/31.06).CCLS.) and	USPAT; US-PGPUB;	2004/08/06 14:41
		(gallium adj nitride))) and passivation	EPO; JPO;	
		, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	DERWENT;	
			IBM_TDB	
1 -	77	(gas adj sensor) and (hfet or misfet or	USPAT;	2004/08/09 09:46
		mesfet or mishfet or (schottky adj diode))	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	34	((gas adj sensor) and (hfet or misfet or	USPĀT;	2004/08/06 14:41
		mesfet or mishfet or (schottky adj	US-PGPUB;	
		diode))) and (silicon adj carbide)	EPO; JPO;	
			DERWENT;	
_	7	((gas adj sensor) and (hfet or misfet or	<pre>IBM_TDB USPAT;</pre>	2004/08/06 14:41
	' !	mesfet or mishfet or (schottky adj	US-PGPUB;	
		diode))) and (gallium adj nitride)	EPO; JPO;	
			DERWENT;	
	, ,	(1111)	IBM_TDB	0004/00/05 ** :5
_	14	((((gas adj sensor) and (hfet or misfet or mesfet or mishfet or (schottky adj	USPAT;	2004/08/06 14:43
		diode))) and (silicon adj carbide)) or	US-PGPUB; EPO; JPO;	
		(((gas adj sensor) and (hfet or misfet or	DERWENT;	
		mesfet or mishfet or (schottky adj	IBM_TDB	
		diode))) and (gallium adj nitride))) and	_	
		passivation	110.Dr	2004/00/06 1: :-
-	9	("4862197" "4984446" "5236569" "5434551" "5447618" "5545300"	USPAT	2004/08/06 14:46
		"5434551" "5447618" "5545300" "5787866" "5976335" "5976350").PN.		
-	1	6051854.URPN.	USPAT	2004/08/06 14:47
-	4	("5216249" "5285084" "5362975"	USPAT	2004/08/06 14:49
		"5493131").PN.		4.
-	4	5656827.URPN.	USPAT	2004/08/06 14:51
	16	4158807.URPN.	USPAT	2004/08/06 14:52

	· · · · · · · · · · · · · · · · · · ·			
-	6	("5424227" "5990531" "6298079"	USPAT	2004/08/06 15:46
		"6316793" "6479843" "6486502").PN. 6690042.URPN.	HCDAM	2004/08/06 15:49
-	0 11	6690042.0RPN. ("4007624" "4244918" "4324218"	USPAT USPAT	2004/08/06 15:49
-	11	"4351182" "4453126" "4706493"	USFAI	2004/08/00 13:30
	ľ	"4931851" "5250170" "5296196"		
		"5298223" "5431883").PN.		
l _	21	5698771.URPN.	USPAT	2004/08/06 15:59
_	30	("4777019" "4778769" "4877582"	USPAT	2004/08/06 16:04
	1	"4894339" "5039390" "5219577"	OSIAI	2004/00/00 10:04
	İ	"5408106" "5420746" "5543351"		
		"5571376" "5576563" "5646420"		
		"5653939" "5747839" "5828076"		
		"5844834" "5892252" "5900728"		
		"5900729" "5922537" "5923046"		
		"5989947" "5997958" "6057556"		
		"6066265" "6103868" "6121075"		
1		"6159620" "6211530" "6483125").PN.		
_	24	("4777019" "4778769" "4877582"	USPAT	2004/08/06 16:56
		"4894339" "5039390" "5219577"		
1		"5420746" "5576563" "5646420"		
-		"5653939" "5747839" "5844834"		
		"5892252" "5899734" "5900728"		
		"5900729" "5922537" "5989947"		
	-	"5997958" "6057556" "6066265"		
		"6103868" "6121075" "6159620").PN.		
-	18	("4126532" "4343768" "4457161"	USPAT	2004/08/06 16:57
		"4928513" "5248385" "5618496"		
!		"5698771" "5915194" "6027954"		
		"6109094" "6161421" "6165874"		
		"6291838" "6297138" "6298710"		
		"6378355" "6461944" "6488771"		
	1	"2001/0015170" "2001/0032493"		
	_	"2002/0019117" "2002/0020853").PN.		
- ,	7	("4982243" "5002899" "5086014"	USPAT	2004/08/06 17:00
		"5132749" "5144380" "5173761"		
	_	"5252294").PN.		0004/00/06 17 00
-	7	("4982243" "5002899" "5086014"	USPAT	2004/08/06 17:00
	-	"5132749" "5144380" "5173761"		
	10	"5252294").PN.	tion»m	2004/09/06 17:01
-	12	5362975.URPN.	USPAT	2004/08/06 17:01
-	14	("3597270" "3645785" "3660154"	USPAT	2004/08/06 17:02
		"4622736" "5270252" "5362975" "5399883" "5442200" "5612232"		
		"5399883" "5442200" "5612232" "5635412" "5656827" "5929523"		
	1	"5035412" "5050827" "5929323" "6027954" "6109094").PN.		
I _	2	6291838.URPN.	USPAT	2004/08/06 17:03
_	29		USPAT;	2004/08/06 17:05
	29	flip\$1chip or (flip adj chip))	US-PGPUB;	2004,00,00 17.05
	1	tripyronip or (rith aal onip))	EPO; JPO;	,
			DERWENT;	
1			IBM TDB	
1 -	9	((438/49).CCLS.) and ((silicon adj	USPAT;	2004/08/09 09:45
		carbide) or (gallium adj nitride))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM TDB]
_	6	(438/49.ccls.) and (hfet or misfet or	USPAT;	2004/08/09 09:47
		mesfet or mishfet or (schottky adj diode))	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
	!		IBM TDB	
-	0	mishfet and (gas adj sensor)	USPĀT;	2004/08/09 14:55
			US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
		,	IBM_TDB	

_	22	encapsulation and gate and (gas adj	USPAT;	2004/08/09 14:55
		sensor)	US-PGPUB;	
	!		EPO; JPO;	
			DERWENT;	İ
		//055/050	IBM_TDB	0000 (00 (00 05 10
_	339	((257/253) or (438/49)).CCLS.	USPAT;	2004/08/09 15:12
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	10	(((257/253) or (438/49)).CCLS.) and	USPAT;	2004/08/09 15:13
		lanthanum	US-PGPUB;	
			EPO; JPO;	. [
			DERWENT;	
_	24	73/31.06 and lanthanum	IBM_TDB USPAT:	2004/08/09 15:13
_	24	73/31.00 and lanchanum	US-PGPUB;	2004/08/09 15:13
			EPO; JPO;	
			DERWENT;	
		•	IBM_TDB	
-	6	,	USPAT	2004/08/09 15:17
		"5306411" "5397541" "5582710").PN.		